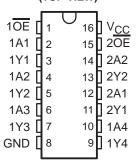
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- EPIC<sup>™</sup> (Enhanced-Performance Implanted CMOS) Process
- Inputs Are TTL-Voltage Compatible
- True Outputs
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), and Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

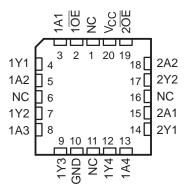
### description

The 'AHCT367 devices are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. These devices are organized as dual 4-line and 2-line buffers/drivers with active-low output-enable (1OE and 2OE) inputs. When OE is low, the device passes noninverted data from the A inputs to the Y outputs. When OE is high, the outputs are in the high-impedance state.

SN54AHCT367 . . . J OR W PACKAGE SN74AHCT367 . . . D, DB, DGV, N, OR PW PACKAGE (TOP VIEW)



SN54AHCT367 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHCT367 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AHCT367 is characterized for operation from –40°C to 85°C.

## FUNCTION TABLE (each buffer/driver)

INP	JTS	OUTPUT
OE	Α	Υ
Н	Χ	Z
L	Н	Н
L	L	L



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

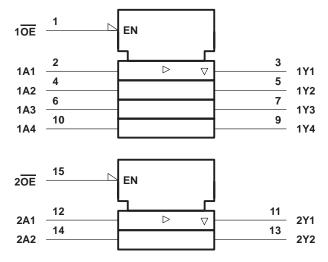
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### SN54AHCT367, SN74AHCT367 HEX BUFFERS AND LINE DRIVERS WITH 3-STATE OUTPUTS

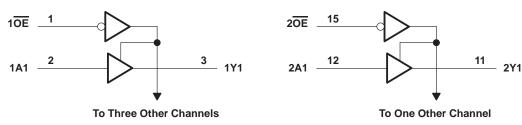
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### logic symbol<sup>†</sup>



<sup>&</sup>lt;sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, DGV, J, N, PW, and W packages.

### logic diagram (positive logic)



Pin numbers shown are for the D, DB, DGV, J, N, PW, and W packages.

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V <sub>CC</sub>		–0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)		–0.5 V to 7 V
Output voltage range, VO (see Note 1)		0.5 V to V <sub>CC</sub> + 0.5 V
Input clamp current, $I_{IK}(V_I < 0)$		–20 mA
Output clamp current, IOK (VO < 0 or VO > VCO	c)	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$		
Continuous current through V <sub>CC</sub> or GND		±75 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 2)	): D package	73°C/W
	DB package	82°C/W
	DGV package	120°C/W
	N package	67°C/W
	PW package	108°C/W
Storage temperature range, T <sub>stg</sub>		–65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
  - 2. The package thermal impedance is calculated in accordance with JESD 51.



### recommended operating conditions (see Note 3)

		SN54AH	CT367	SN74AHCT367		UNIT
		MIN	MAX	MIN	MAX	UNII
VCC	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2	7	2		V
V <sub>IL</sub>	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	5.5	0	5.5	V
٧o	Output voltage	0	VCC	0	Vcc	V
ІОН	High-level output current	22	-8		-8	mA
loL	Low-level output current	70	8		8	mA
Δt/Δν	Input transition rise or fall rate	Q	20		20	ns/V
TA	Operating free-air temperature	-55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	vcc	T <sub>A</sub> = 25°C			SN54AHCT367		SN74AHCT367		UNIT
PARAMETER			MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
VOH	I <sub>OH</sub> = -50 μA	4.5 V	4.4	4.5		4.4		4.4		V
	$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		3.8		٧
Voi	I <sub>OL</sub> = 50 μA	4.5 V			0.1		0.1		0.1	V
VOL	I <sub>OL</sub> = 8 mA	4.5 V			0.36		0.44		0.44	٧
lį	$V_I = V_{CC}$ or GND	0 V to 5.5 V			±0.1*		€ ±1*		±1	μΑ
loz	$V_I = V_{CC}$ or GND, $V_O = V_{CC}$ or GND, $\overline{OE} = V_{IH}$	5.5 V			±0.25	(C) (S)	±2.5		±2.5	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4	201	40		40	μΑ
∆l <sub>CC</sub> †	One input at 3.4 V, Other inputs at V <sub>CC</sub> or GND	5.5 V		·	1.35	NA PA	1.5		1.5	mA
Ci	$V_I = V_{CC}$ or GND	5 V		2.5	10		10		10	pF
Co	$V_O = V_{CC}$ or GND	5 V		5						pF

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested at  $V_{CC} = 0 \text{ V}$ .

<sup>†</sup> This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V<sub>CC</sub>.

### SN54AHCT367, SN74AHCT367 HEX BUFFERS AND LINE DRIVERS WITH 3-STATE OUTPUTS

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# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	FROM TO LOAD		T,	T <sub>A</sub> = 25°C		SN54AHCT367		SN74AHCT367		UNIT																	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT																	
t <sub>PLH</sub>	Α	Y	C <sub>L</sub> = 15 pF		2.5*	4.8*	1*	6.5*	1	5.5	ns																	
t <sub>PHL</sub>	A	'	CL = 13 μ		2.5*	4.8*	1*	6.5*	1	5.5	115																	
<sup>t</sup> PZH	ŌĒ	Y	C <sub>L</sub> = 15 pF		3.5*	8*	1*	9.5*	1	8.5	ns																	
t <sub>PZL</sub>	OE	ī	CL = 15 pr		2.8*	7*	1*	8.5*	1	7.5	115																	
t <sub>PHZ</sub>	ŌĒ	Y	C <sub>I</sub> = 15 pF		3.1*	8*	1*	9.5*	1	8.5	ns																	
tPLZ		ī	CL = 15 pr		2.8*	7*	1*,0	8.5*	1	7.5	115																	
tPLH	Α	Υ	C. = 50 pE		3.5	5.8	(a)	7.5	1	6.5	ns																	
t <sub>PHL</sub>	A	Ť	<b>1</b>	T T	Ť	l ,	Ť		<u> </u>	l t	ľ	ſ	ľ	ľ	ľ	ľ	f	7	Ť	$C_L = 50 \text{ pF}$		3.3	5.8	Q1	7.5	1	6.5	115
<sup>t</sup> PZH	ŌĒ	Y	C <sub>I</sub> = 50 pF		4.5	9	2 1	10.5	1	9.5	no																	
tPZL	] OE	ſ	CL = 50 pr		3.7	8	1	9.5	1	8.5	ns																	
t <sub>PHZ</sub>	OE	Y	C: - 50 pE		4.1	9	1	10.5	1	9.5	ne																	
t <sub>PLZ</sub>	OL	ſ	C <sub>L</sub> = 50 pF		3.6	8	1	9.5	1	8.5	ns																	

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.

## noise characteristics, $V_{CC} = 5 \text{ V}$ , $C_L = 50 \text{ pF}$ , $T_A = 25^{\circ}\text{C}$ (see Note 4)

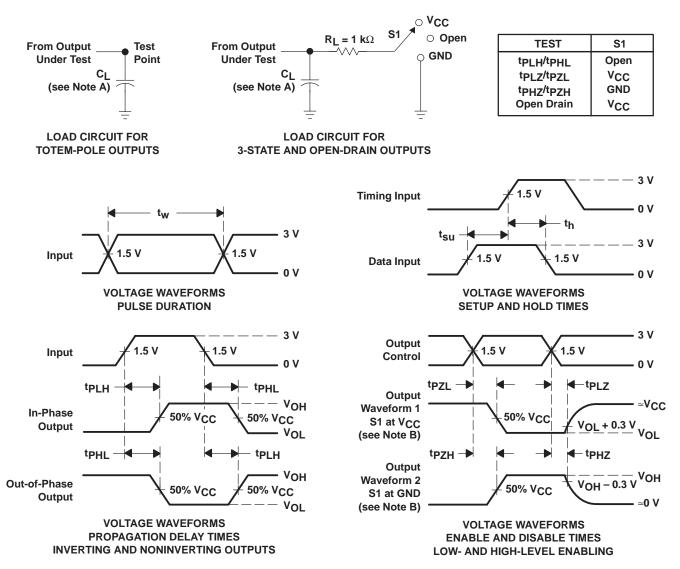
PARAMETER				SN74AHCT367			
	PARAMETER				UNIT		
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.4		V		
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		-0.4		V		
VOH(V)	Quiet output, minimum dynamic VOH		4.7		V		
VIH(D)	High-level dynamic input voltage	2			V		
V <sub>IL(D)</sub>	Low-level dynamic input voltage			0.8	V		

NOTE 4: Characteristics are for surface-mount packages only.

## operating characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST C	ONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	No load,	f = 1 MHz	22	pF

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_Q = 50 \Omega$ ,  $t_f \leq$  3 ns,  $t_f \leq$  3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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